Specifications

Technical Specifications - 1732DS-IB8X0BV4, 1732DS-IB8

Attribute	1732DS-IB8X0BV4, 1732DS-IB8
Safety Input	
Input type	Current sinking
Voltage, on-state input, min	11V DC
Current, on-state input, min	3.3 mA
Voltage, off-state input, max	5V DC
Current, off-state, max	1.3 mA
IEC 61131-2 (input type)	Туре 3
Pulse Test Output	
Output type	Current sourcing
Pulse test output current	0.7 A
Residual voltage, max	1.2V
Output leakage current, max	0.1 mA
Short circuit protection	Yes
Current, max	25 mA - Current, max (to avoid fault when used as a muted lamp output)
Current, min	5 mA - Current, min (at which fault indication is generated when used as a muted lamp output)
Safety Output (1732DS-IB8	XOBV4 module only)
Output types	Current sourcing/current sinking - bipolar pair
Output current rating	2 A max per point 8 A total module @ 40 °C (104 °F) 6 A total module @ 60 °C (140 °F)
On-state voltage drop	±0.6V
Leakage current	±1.0 mA ⁽¹⁾

Attribute	1732DS-IB8X0BV4, 1732DS-IB8
Internal resistance from P to M terminal	3.25 kΩ
Short circuit detection	Yes (short high and low and cross-circuit fault detect)
Short circuit protection	Electronic
Aggregate current of outputs per module	8 A @ 40 °C (104°F) 6 A @ 60 °C (140 °F)
Pilot duty rating	DC-14 Pilot Duty (1732DS-IB8XOBV4 module only)
Number of outputs	4 dual channel

Technical Specifications - 1732DS-IB8XOBV4, 1732DS-IB8

(1) Includes the presence of a single P stuck-high or M stuck-low short.

General Specifications - 1732DS-IB8XOBV4, 1732DS-IB8

Attribute	1732DS-IB8X0BV4, 1732DS-IB8
Enclosure type rating	Meets IP64/65/66/67/69K (when product is marked)
Communication power supply voltage	1125V DC (supplied from communication power supply)
Communication current consumption	85 mA at 24V DC
Operating voltage range	19.228.8V DC (24V DC, -2020%)
Isolation voltage	50V (continuous), reinforced insulation type, I/O to DeviceNet network, I/O to power, and power to DeviceNet network, Tested at 750V DC for 60s